## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of		
Pendharkar	(TI-34637)	
Serial No/		Group Art Unit:
Filed: Herewith		Examiner:
For: Drain Extended MOS Transistor with Improved Breakdown Robustness		

## **PRELIMINARY AMENDMENT**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Dear Sir:

## **Introductory Comments:**

This paper is presented prior to the examination of this application. Entry of this amendment prior to examination is respectfully requested.

Amendment to the claims begins on page 2.

Applicant's remarks begin on page 7.